

# DIODE MODULE (F.R.D.)

## DD250GB

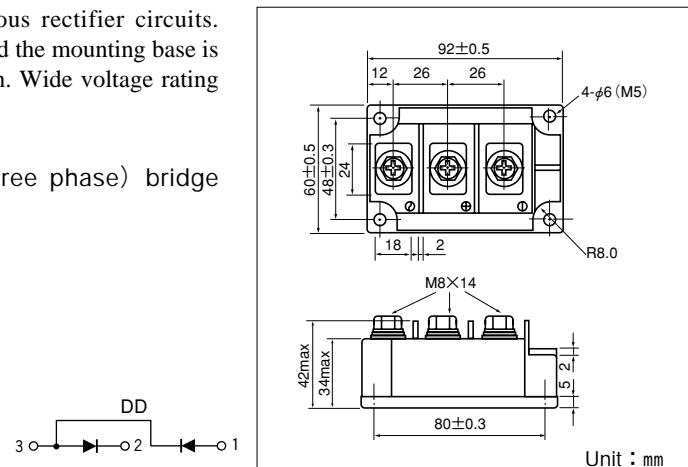
UL:E76102(M)

Power Diode Module **DD250GB** series are designed for various rectifier circuits. **DD250GB** has two diode chips connected in series in a package and the mounting base is electrically isolated from elements for simple heatsink construction. Wide voltage rating up to 800V is available for various input voltage.

- Isolated mounting base
- Two elements in a package for simple (single and three phase) bridge connections
- Highly reliable glass passivated chips
- High surge current capability

### (Applications)

Various rectifiers, Battery chargers, DC motor drives



(T<sub>j</sub>=25°C unless otherwise specified)

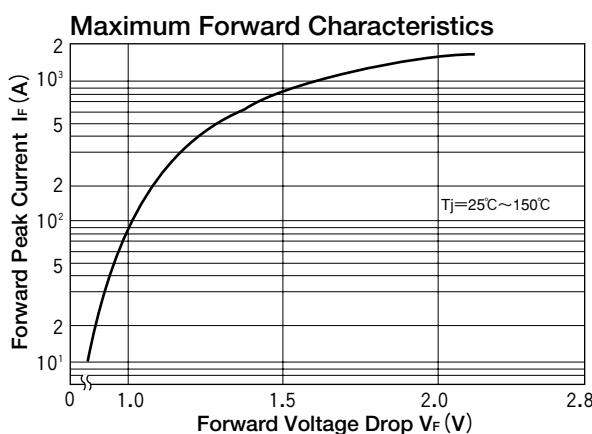
### ■ Maximum Ratings

| Symbol           | Symbol                              | Ratings   |           | Unit |
|------------------|-------------------------------------|-----------|-----------|------|
|                  |                                     | DD250GB40 | DD250GB80 |      |
| V <sub>RRM</sub> | Repetitive Peak Reverse Voltage     | 400       | 800       | V    |
| V <sub>RSM</sub> | Non-Repetitive Peak Reverse Voltage | 480       | 960       | V    |

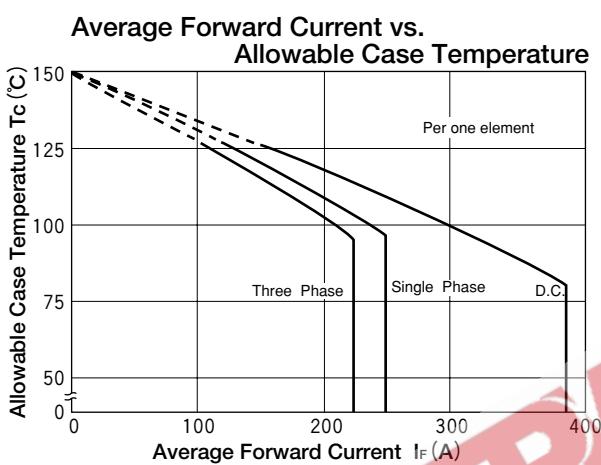
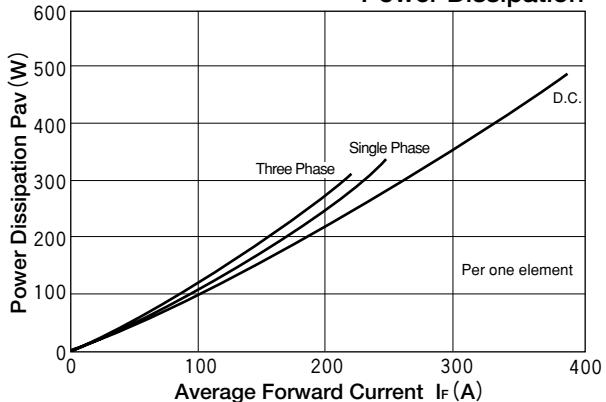
| Symbol              | Symbol                               | Conditions   | Ratings     | Unit             |
|---------------------|--------------------------------------|--|-------------|------------------|
| I <sub>F(AV)</sub>  | Average Forward Current              | Single phase, half wave, 180°C conduction, T <sub>c</sub> : 98°C | 250         | A                |
| I <sub>F(RMS)</sub> | R.M.S. Forward Current               | Single phase, half wave, 180°C conduction, T <sub>c</sub> : 98°C | 390         | A                |
| I <sub>FSM</sub>    | Surge Forward Current                | ½ cycle, 50/60Hz, peak value, non-repetitive                     | 5000/5500   | A                |
| I <sup>2</sup> t    | I <sup>2</sup> t                     | Value for one cycle of surge current                             | 125000      | A <sup>2</sup> S |
| T <sub>j</sub>      | Operating Junction Temperature       |  | -40 to +150 | °C               |
| T <sub>stg</sub>    | Storage Temperature                  |  | -40 to +125 | °C               |
| V <sub>iso</sub>    | Isolation Breakdown Voltage (R.M.S.) | A.C. 1 minute  | 2500        | V                |
| Mounting Torque     | Mounting (M5)                        | Recommended Value 1.5-2.5 (15-25)                                | 2.7 (28)    | N·m              |
|                     | Terminal (M8)                        | Recommended Value 8.8-10 (90-105)                                | 11 (115)    | (kgf·cm)         |
| Mass                |                                      | Typical Value  | 510         | g                |

### ■ Electrical Characteristics

| Symbol               | Symbol                          | Conditions   | Ratings |      |      | Unit |
|----------------------|---------------------------------|--|---------|------|------|------|
|                      |                                 |  | Min.    | Typ. | Max. |      |
| I <sub>RRM</sub>     | Repetitive Peak Reverse Current | T <sub>j</sub> =150°C at V <sub>RRM</sub>                      |         |      | 50   | mA   |
| V <sub>FM</sub>      | Forward Voltage Drop            | T <sub>j</sub> =25°C, I <sub>FM</sub> =750A, Inst. measurement |         |      | 1.45 | V    |
| R <sub>th(j-c)</sub> | Thermal Impedance               | Junction to case   |         |      | 0.14 | °C/W |



Average Forward Current vs.  
Power Dissipation



Cycle Surge Forward Current Rating  
(Non-Repetitive)

